



The Future of Analog IC Technology®

MP2009

Ultra-Low-Noise Low-Dropout, 120mA Linear Regulator

DESCRIPTION

The MP2009 is an ultra low noise, low dropout linear regulator. The output voltage of MP2009 ranges from 1.5V to 4.5V in 100mV increments and 1% accuracy by operating from a +2.0V to +6.0V input. It is designed to deliver up to 120mA continuous output current. It achieves a low 120mV dropout for full load current.

The MP2009 uses an internal PMOS as the pass element, which consumes 50 μ A supply current at no load condition. New innovative design techniques make MP2009 achieve ultra-low output voltage noise of 16 μ V_{RMS} without a noise bypass capacitor.

The MP2009 are designed and optimized to work with low value, low cost ceramic capacitors in space-limiting and performance consideration. It requires only 1 μ F (typ) of output capacitance for stability with any load. It is available in a 5-pin SC70 package.

FEATURES

- Space-Saving SC70 Package
- 16 μ V_{RMS} Output Noise (100Hz to 30kHz) No Bypass Capacitor Required
- 78dB PSRR at 1kHz
- 120mV Dropout at 120mA Load
- Stable with 1 μ F Ceramic Capacitor for Any Load
- Low 50 μ A Ground Current
- Very Fast Line and Load Transient Response with Small Input and Output Capacitor
- Current Limit and Thermal Protection

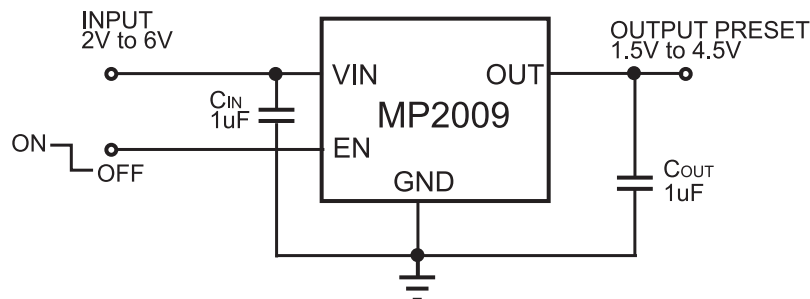
APPLICATIONS

- Cellular and Cordless Phones
- VCOs
- PDA and Palmtop Computers
- Digital Cameras
- Base Stations
- Wireless LANs
- Bluetooth Portable Radios and Accessories
- Portable and Battery-Powered Equipment

All MPS parts are lead-free and adhere to the RoHS directive. For MPS green status, please visit MPS website under Products, Quality Assurance page.

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TYPICAL APPLICATION



ORDERING INFORMATION

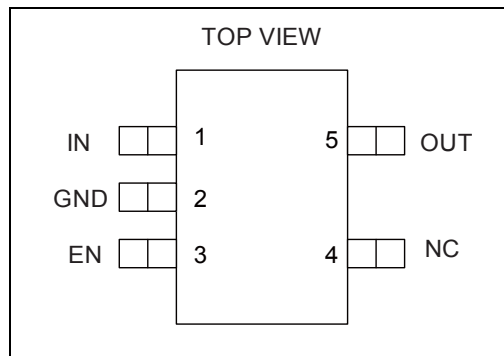
Part Number**	Package	VOUT(V)	Top Marking	Free Air Temperature Range (T _A)
MP2009EE-1.5*	5-SC70	1.5		-20°C to +85°C
MP2009EE-1.8		1.8	8B	
MP2009EE-2.5		2.5	AQ	
MP2009EE-2.6		2.6		
MP2009EE-2.7		2.7		
MP2009EE-2.8		2.8		
MP2009EE-2.85		2.85		
MP2009EE-3		3		
MP2009EE-4.0		4.0	CG	
MP2009EE-4.5		4.5		

* For Tape & Reel, add suffix -Z (eg. MP2009EE-1.5-Z).

For Lead Free, add suffix -LF (eg. MP2009EE-1.5-LF-Z)

** Available options are identified by those with top marking. For other options, please contact factory to check availability.

PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Supply Input Voltage	6.5V
Power Dissipation, P _D @ T _A =25°C ⁽²⁾	
5-SC70	0.385W
Operation Temperature Range	-20°C to 85°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering, 10sec)	300°C

Recommended Operating Conditions ⁽³⁾

Supply Input Voltage.....	2.0V to 6.0V
Enable Input Voltage	0V to 6.0V
Operating Junction Temp (T _J) .-	40°C to +125°C

Thermal Resistance ⁽⁴⁾	θ_{JA}	θ_{JC}
5-SC70.....	260.....	130 °C/W

Notes:

- Exceeding these ratings may cause permanent damage to the device.
- The maximum allowable power dissipation is a function of the maximum junction temperature, T_{J(MAX)}, the junction-to-ambient thermal resistance, θ_{JA}, and the ambient temperature, T_A. The maximum allowable power dissipation at any ambient temperature is calculated using: P_{D(MAX)}=(T_{J(MAX)}-T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at T_J=150°C(typ) and disengages at T_J=130°C (typ).
- The device is not guaranteed to function outside its operating conditions.
- Measured on JESD51-7 4-layer board.

ELECTRICAL CHARACTERISTICS

$V_{IN} = V_{OUT} + 0.5V$, $V_{EN} = V_{IN}$, and $C_{IN} = 1\mu F$, $C_{OUT} = 1\mu F$, Typical values are at $T_A = 25^\circ C$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Input Voltage Range	V_{IN}		2		6	V
Output Voltage Accuracy		$I_{OUT} = 1mA, T_A = 25^\circ C$	-1		1	%
		$I_{OUT} = 100\mu A \text{ to } 80mA, T_A = 25^\circ C$	-2		2	
		$I_{OUT} = 100\mu A \text{ to } 80mA, T_A = -20^\circ C \sim 85^\circ C$		± 3		
Maximum Output Current	I_{OUT}		120			mA
Current Limit	I_{LIM}	$V_{OUT} = 1.8V$ OUT=90% of nominal value	130	200	300	mA
		$V_{OUT} = 2.5V$ OUT=90% of nominal value	160	230	330	mA
		$V_{OUT} = 3.3V$ OUT=90% of nominal value	180	250	350	mA
		$V_{OUT} = 4.0V$ OUT=90% of nominal value	200	270	370	mA
Dropout Voltage ⁽⁵⁾		$V_{OUT} = 1.8V, I_{OUT} = 80mA$		115	240	mV
		$V_{OUT} = 1.8V, I_{OUT} = 120mA$		172		mV
		$V_{OUT} = 2.5V, I_{OUT} = 80mA$		100	220	mV
		$V_{OUT} = 2.5V, I_{OUT} = 120mA$		140		mV
		$V_{OUT} = 3.3V, I_{OUT} = 80mA$		80	200	mV
		$V_{OUT} = 3.3V, I_{OUT} = 120mA$		120		mV
		$V_{OUT} = 4.0V, I_{OUT} = 80mA$		70	180	mV
		$V_{OUT} = 4.0V, I_{OUT} = 120mA$		110		mV
Ground Current	I_Q	$I_{OUT} = 0.05mA$		50	90	μA
		$V_{IN} = V_{OUT} - 0.1V, I_{OUT} = 0mA$		50	90	
Line Regulation ⁽⁶⁾	V_{LNR}	$V_{IN} = V_{OUT} + 0.5V \text{ to } 6V$ $I_{OUT} = 0.1mA$		0.03		%/V
Load Regulation ⁽⁷⁾	V_{LDR}	$I_{OUT} = 1mA \text{ to } 120mA$		0.002		%/mA
Shutdown Supply Current	I_{SHDN}	$V_{EN} = 0$	$T_A = 25^\circ C$	0.01	1	μA
			$T_A = 85^\circ C$	0.2		
Ripple Rejection	PSRR	$F = 1kHz, I_{OUT} = 10mA$		78		dB
		$F = 10kHz, I_{OUT} = 10mA$		75		
		$F = 100kHz, I_{OUT} = 10mA$		55		
Output Noise Voltage		$F = 100Hz \text{ to } 30kHz$ $I_{LOAD} = 10mA$		16		μV_{RMS}
		$F = 100Hz \text{ to } 30kHz$ $I_{LOAD} = 80mA$		17		
EN Startup delay ⁽⁸⁾		$R_{LOAD} = 50\Omega$			150	μs
V_{EN} Logic Low Level		$V_{IN} = 2V \text{ to } 6V$	$T_A = 25^\circ C$		0.4	V
			$T_A = 85^\circ C$		0.3	
V_{EN} Logic High Level		$V_{IN} = 2V \text{ to } 6V$	1.5			V

ELECTRICAL CHARACTERISTICS (continued)

$V_{IN} = V_{OUT} + 0.5V$, $V_{EN} = V_{IN}$, and $C_{IN} = 1\mu F$, $C_{OUT} = 1\mu F$, Typical values are at $T_A = 25^\circ C$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Units
V _{EN} Input Bias Current		V _{IN} =6V, V _{EN} =6V	T _A =25°C		1	μA
			T _A =85°C		0.01	
Thermal Shutdown ⁽⁹⁾				150		°C
Thermal Shutdown Hysteresis				20		°C

Notes:

5) Dropout is defined as $V_{IN} - V_{OUT}$ when V_{OUT} is 100mV below the value of V_{OUT} for $V_{IN} = V_{OUT} + 0.5V$.

$$6) \text{ Line Regulation} = \frac{|V_{OUT[V_{IN(MAX)}]} - V_{OUT[V_{IN(MIN)}]}|}{(V_{IN(MAX)} - V_{IN(MIN)}) \times V_{OUT(NOM)}} \times 100(\%/V)$$

$$7) \text{ Load Regulation} = \frac{|V_{OUT[I_{OUT(MAX)}]} - V_{OUT[I_{OUT(MIN)}]}|}{(I_{OUT(MAX)} - I_{OUT(MIN)}) \times V_{OUT(NOM)}} \times 100(\%/mA)$$

8) Time needed for V_{OUT} to reach 90% of final value.

9) Guaranteed by design, not tested.

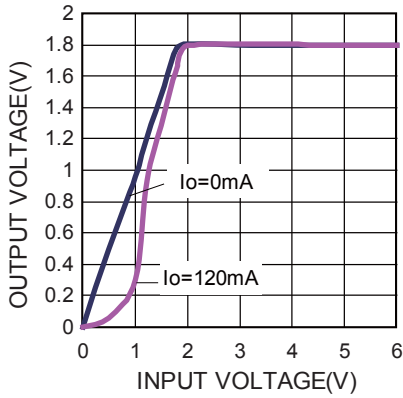
PIN FUNCTIONS

Pin #	Name	Description
1	IN	Input supply
2	GND	Common Ground
3	EN	When enable pin (EN) is high, the regulator turns on; when enable pin (EN) is low, the regulator shutdown.
4	NC	No Connection
5	OUT	Output of the regulator

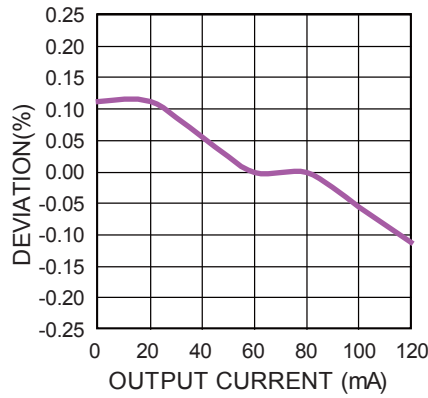
TYPICAL PERFORMANCE CHARACTERISTICS

$V_{IN}=2.3V$, $V_{OUT}=1.8V$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$, $EN=2.3V$, Typical Value at $T_A = 25^\circ C$ unless otherwise specified.

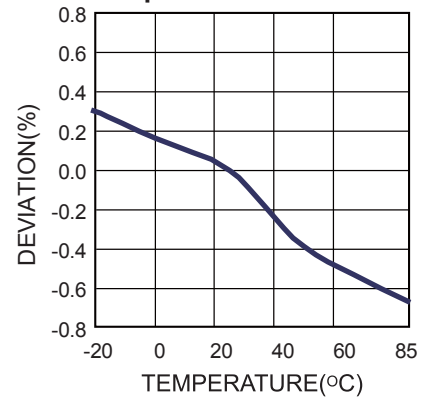
V_{IN} vs. V_{OUT}



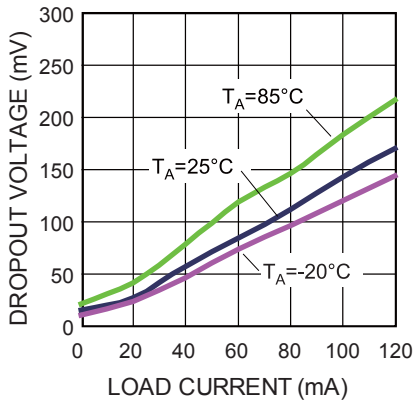
Load Regulation



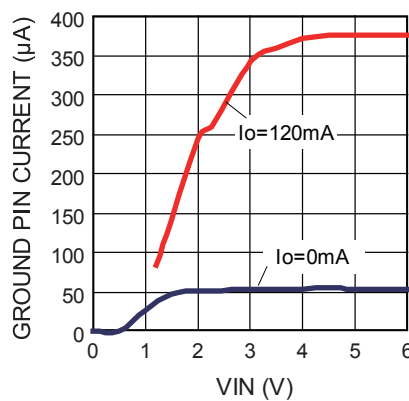
Voltage Accuracy vs. Temperature



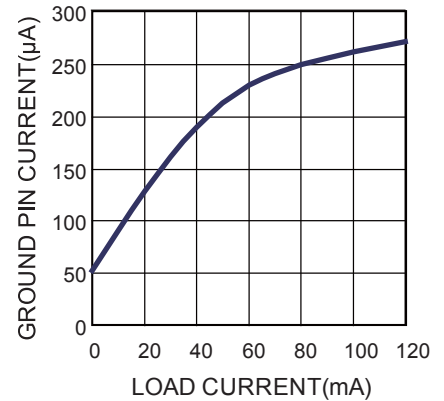
Dropout Voltage vs. Output Current



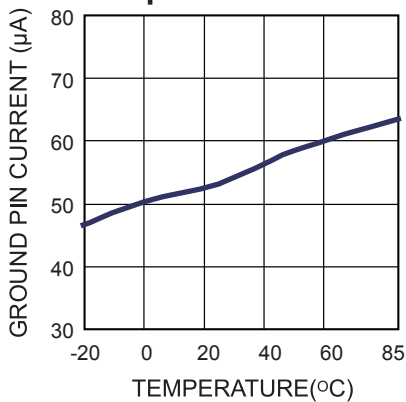
Ground Pin Current vs. V_{IN}



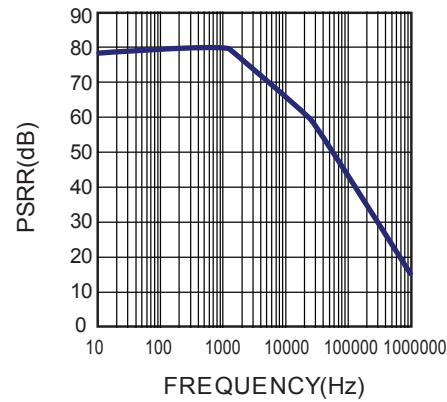
Ground Pin Current vs. Output Current



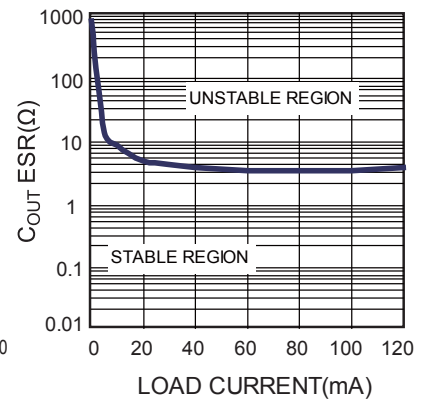
Ground Pin Current vs. Temperature



PSRR vs. Frequency
 $I_{OUT}=10mA$

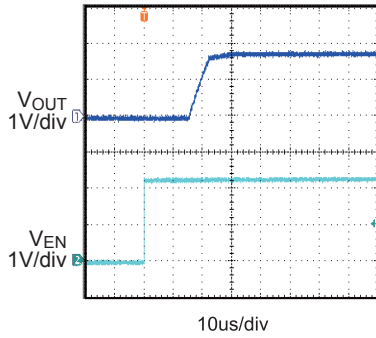
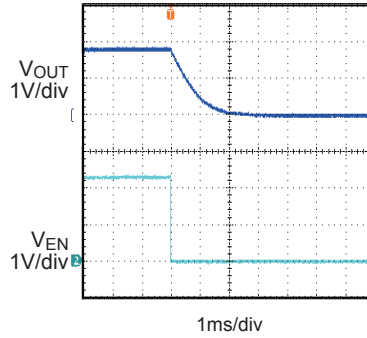
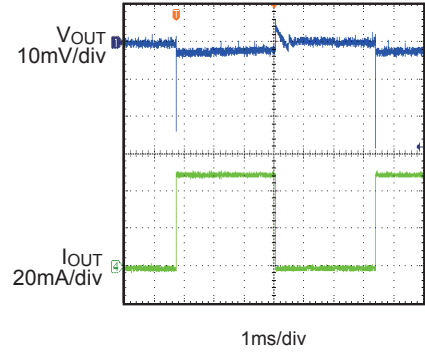


Region of Stable C_{OUT} ESR vs. Load Current

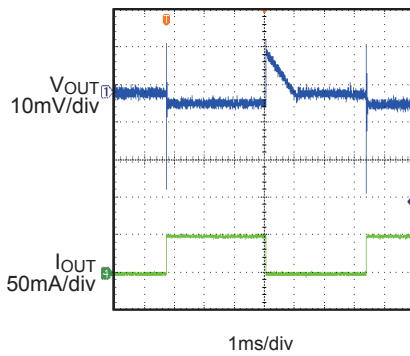


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

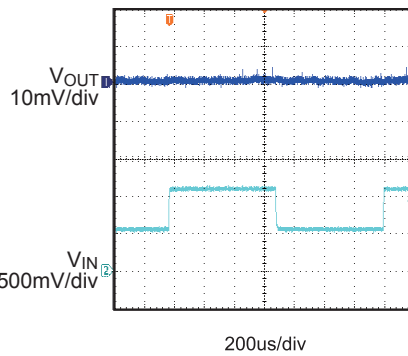
$V_{IN}=2.3V$, $V_{OUT}=1.8V$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$, $EN=2.3V$, Typical Value at $T_A = 25^\circ C$ unless otherwise specified.

EN Startup Waveform

EN Shutdown Waveform

Load Transient Response
 $I_{OUT}=0$ to 50mA

Load Transient Response Near Dropout

$V_{IN}=1.9V$, $I_{OUT}=0$ to 50mA

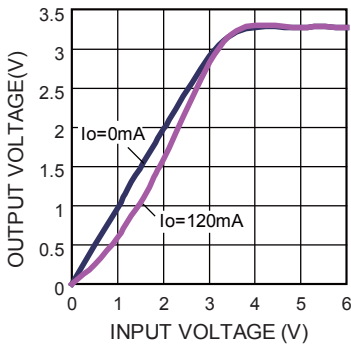
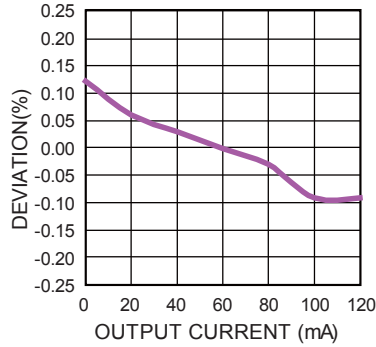
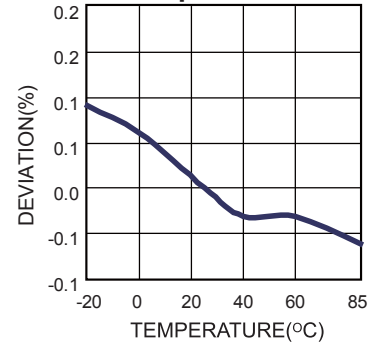
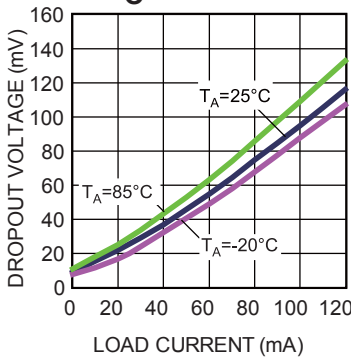
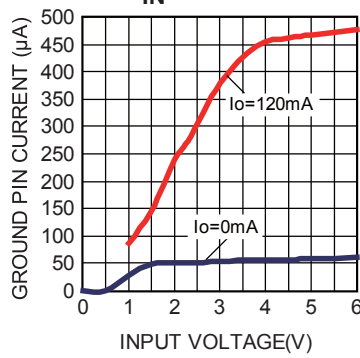
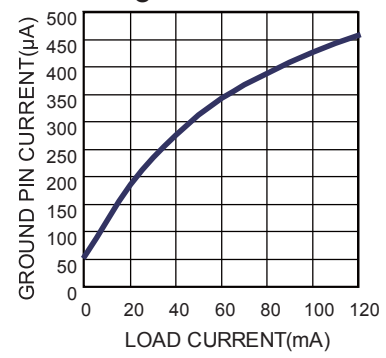
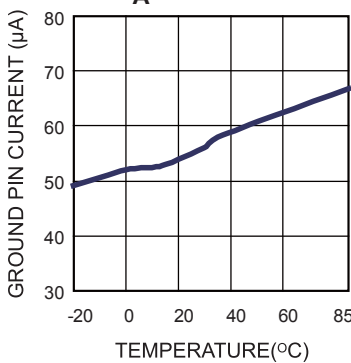
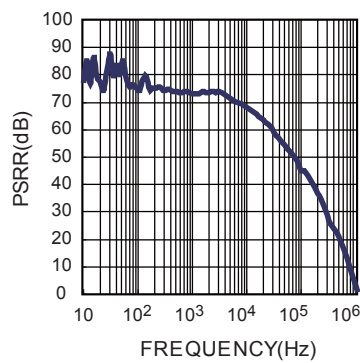
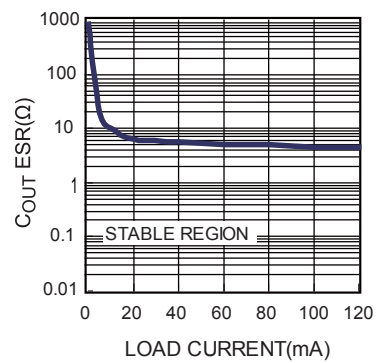

Line Transient Response

$V_{IN}=2.3V$ to 2.8V, $I_{OUT}=0$ mA



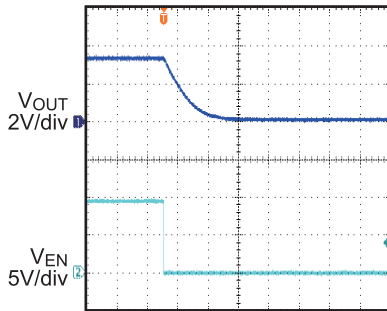
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_{IN}=3.8V$, $V_{OUT}=3.3V$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$, $EN=3.8V$, Typical Value at $T_A = 25^\circ C$ unless otherwise specified.

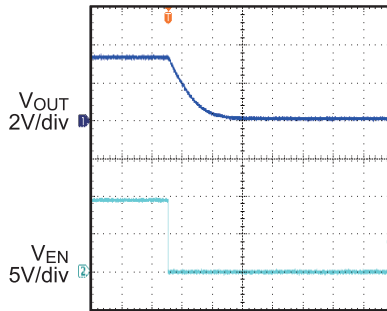
 V_{IN} vs. V_{OUT}

Load Regulation
 $V_{IN}=3.8V$

Output Voltage Accuracy vs. Temperature

Dropout Voltage vs. I_O

Quiescent Current vs. V_{IN}

Quiescent Current vs. I_O

Quiescent Current vs. T_A

PSRR vs. Frequency
 $I_{OUT}=10mA$

Region of Stable C_{OUT} ESR vs. Load Current


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

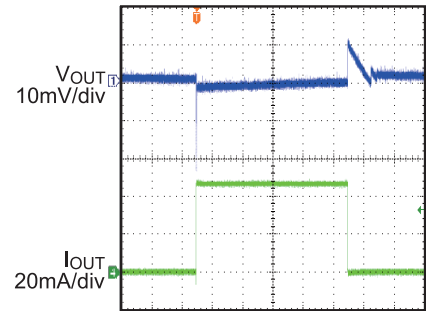
$V_{IN}=3.8V$, $V_{OUT}=3.3V$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$, $EN=3.8V$, Typical Value at $T_A = 25^\circ C$ unless otherwise specified.

EN Startup Waveform
 $I_{OUT}=0mA$


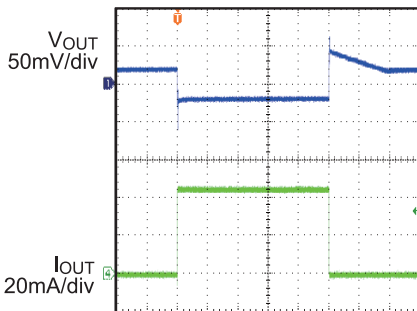
10us/div

EN Shutdown Waveform
 $I_{OUT}=0mA$


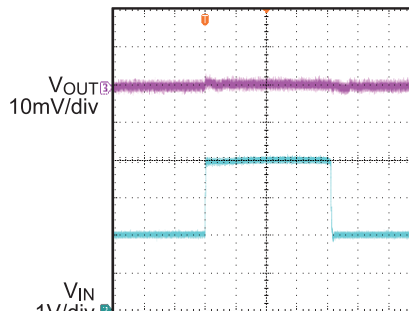
1ms/div

Load Transient Response
 $V_{IN}=3.8V$, $I_{OUT}=0mA$ to 50mA


1ms/div

Load Transient Response Near Dropout
 $V_{IN}=3.2V$, $I_{OUT}=0mA$ to 50mA


1ms/div

Line Transient Response
 $V_{IN}=3.8V$ to 6V, $I_{OUT}=0mA$


200us/div

FUNCTION BLOCK DIAGRAM

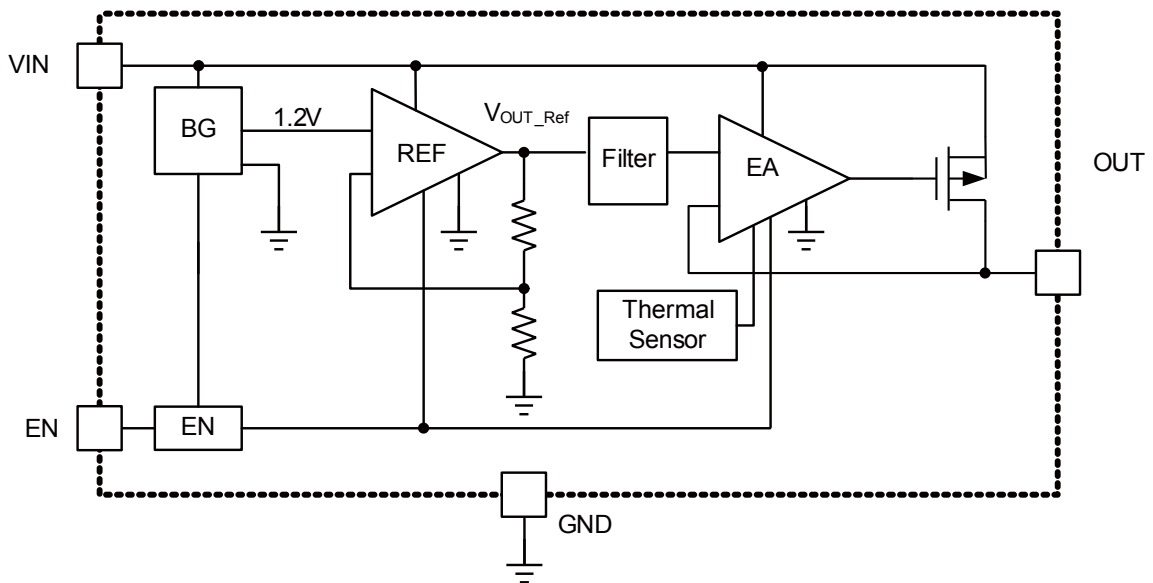


Figure1—Functional Block Diagram

OPERATION

The MP2009 is an ultra low noise, low dropout, low-quiescent current linear regulator designed for space-restricted applications. It is intended for use in devices that requires very low voltage, low quiescent current such as wireless LAN, battery-powered equipment and hand-held equipment.

Internal P-Channel Pass Transistor

The MP2009 features a 1.4Ω P-channel MOSFET as the pass transistor. It provides several advantages over similar designs using PNP pass transistor. The P-channel MOSFET requires no base drive, which reduces quiescent current considerably and increase the battery life. PNP-based regulators waste considerable current in dropout when the pass transistor saturates. They also use high base-drive current under the large load condition. The MP2009 does not suffer from these problems and consume only $50\mu\text{A}$ of quiescent current in light load and dropout mode.

Dropout Voltage

Dropout voltage is the minimum input to output differential voltage required for the regulator to maintain an output voltage within 100mV of its nominal value. It determines the available end-of-life battery voltage in battery-powered systems. For the P-channel MOSFET pass element, the dropout voltage is a function of drain to source on resistance. Because the P-channel MOSFET pass element behaves as a low-value resistor, the dropout voltage of MP2009 is very low.

Shutdown

The MP2009 can be switched ON or OFF by a logic input at the EN pin. A high voltage at this pin will turn the device on. When the EN pin is low, the regulator output is off. The EN pin should be tied to VIN to keep the regulator output always on if the application does not require the shutdown feature. Do not float the EN pin.

Current Limit and Thermal Protection

The MP2009 includes an independent current limit structure which monitors and controls the P-channel MOSFET's gate voltage to limit the guaranteed maximum output current to 120mA. Thermal protection turns off the P-channel MOSFET when the junction temperature exceeds $+150^{\circ}\text{C}$, allowing the IC to cool. When the IC's junction temperature drops by 20°C , the PMOS will be turned on again. Thermal protection limits total power dissipation in the MP2009. For reliable operation, junction temperature should be limited to 125°C maximum.

APPLICATION INFORMATION

Power Dissipation

The power dissipation for any package depends on the thermal resistance of the case and circuit board, the temperature difference between the junction and ambient air, and the rate of airflow. The power dissipation across the device can be represented by the equation:

$$P = (V_{IN} - V_{OUT}) \times I_{OUT}$$

The allowable power dissipation can be calculated using the following equation:

$$P_{(MAX)} = (T_{Junction} - T_{Ambient}) / \theta_{JA}$$

Where $(T_{Junction} - T_{Ambient})$ is the temperature difference between the junction and the surrounding environment, θ_{JA} is the thermal resistance from the junction to the ambient environment. Connecting the GND pin of MP2009 to ground with a large ground plane will help the channel heat away.

Output Noise and PSRR

For the MP2009, an internal 50pF bypass capacitor with new innovative structure reduces output noises greatly. It does not need external

bypass capacitor for space-limiting applications. The power supply rejection is 75dB at 10kHz and 55dB at 100kHz. (See the PSRR vs. Frequency graph in the Typical Performance Characteristics).

Input Capacitor Selection

Use a 1 μ F capacitor on the input of the MP2009. Larger values will help to improve line transient response with the drawback of increased size. Ceramic capacitors are preferred, but tantalum capacitors may also suffice.

Output Capacitor Selection

The MP2009 is designed specifically to work with very low ESR ceramic output capacitor in space-limiting and performance consideration. Output capacitor of larger values will help to improve load transient response and reduce noise with the drawback of increased size. A 1 μ F ceramic capacitor with ESR lower than 3 Ω is sufficient for the MP2009 application circuit. (See the Region of Stable C_{OUT} ESR vs. Load Current graph in the Typical Performance Characteristics)

PCB LAYOUT GUIDE

PCB layout is very important to achieve good regulation, ripple rejection, transient response and thermal performance. It is highly recommended to duplicate EVB layout for optimum performance.

If change is necessary, please follow these guidelines and take figure 2 for reference.

1) Input and output bypass ceramic capacitors are suggested to be put close to the IN Pin and OUT Pin respectively.

- 2) Ensure all feedback connections are short and direct. Place the feedback resistors and compensation components as close to the chip as possible.
- 3) Connect IN, OUT and especially GND respectively to a large copper area to cool the chip to improve thermal performance and long-term reliability.

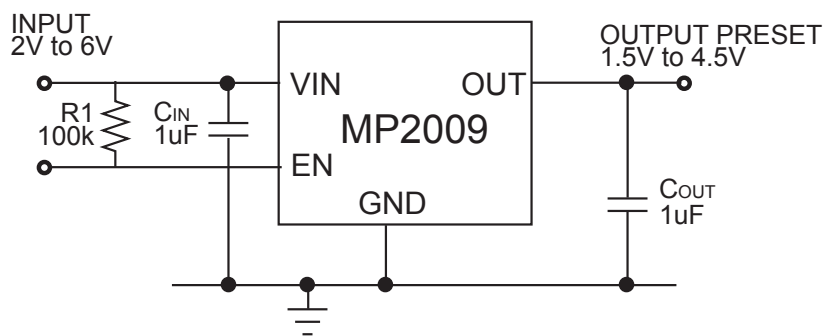


Figure 2 —MP2009 Typical Application Circuit

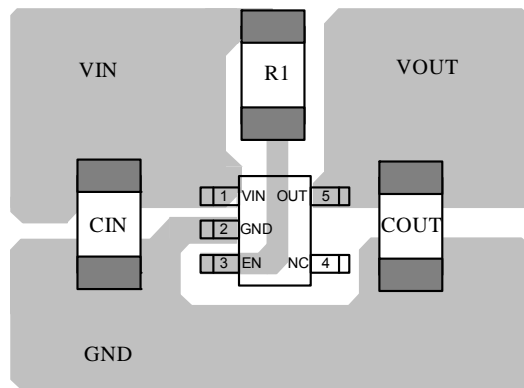


Figure 3—MP2009 Top Layer